Supplementary information

Morphology-Engineered α-MoO_3 Nanostructures via MoS_2 Transformation for High-Performance Supercapacitors

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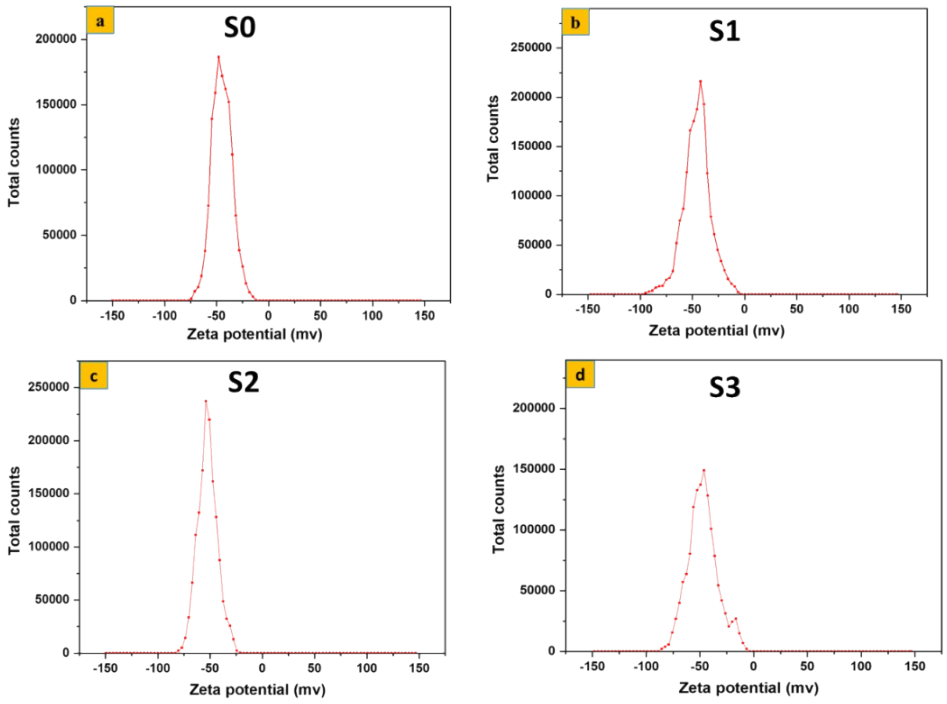

Fig. S1. Zeta potentail profile of synthesized S0, S1, S2, and S3.

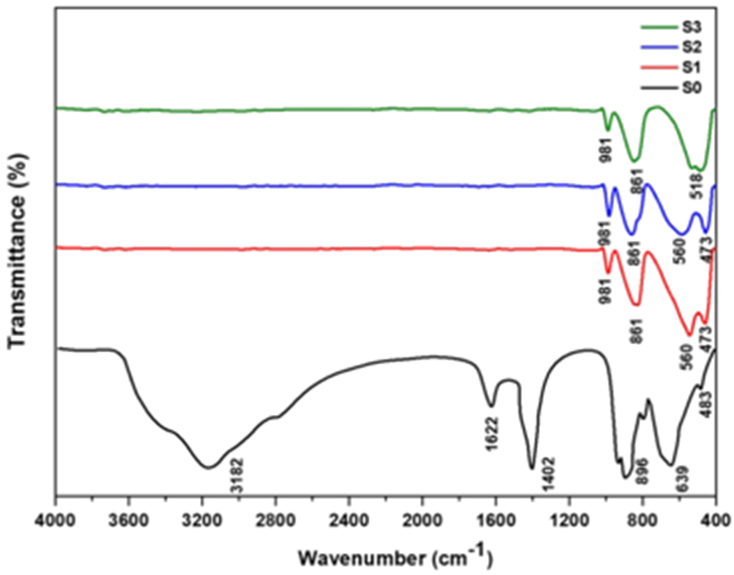

Fig.S2. ATR-IR spectra of of synthesized S0, S1, S2, and S3.

Table S1: Surface area, pore diameter and pore volume of the adsorbents.

Sample	S_{BET} (m^2g^{-1})	Pore Volume ($cm^3\ g^{-1}$)	Pore diameter (nm)
S0	10.44	0 .035	19.75
S1	14.39	0.0967	27.55
S2	3.23	0.036	9.36
S3	12.34	0.071	22.59

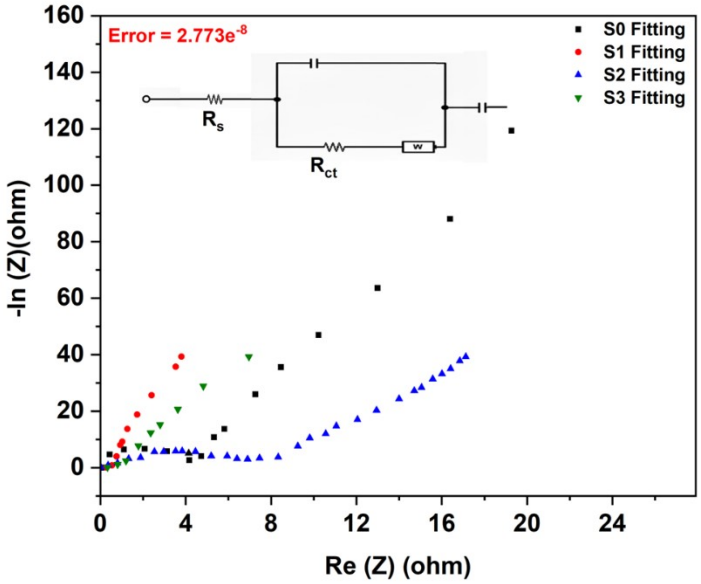

Fig.S3. EIS fitting for S0-S3

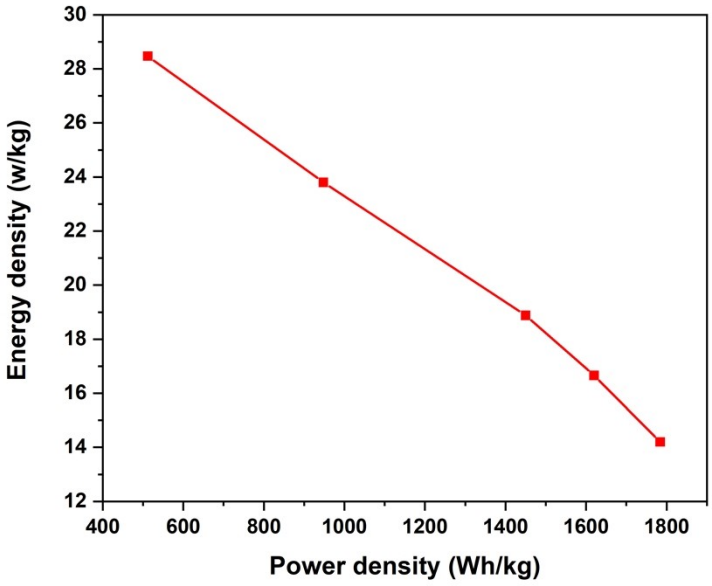

Fig.S4. IR Ragone plot for MoO3-S1 at different current density

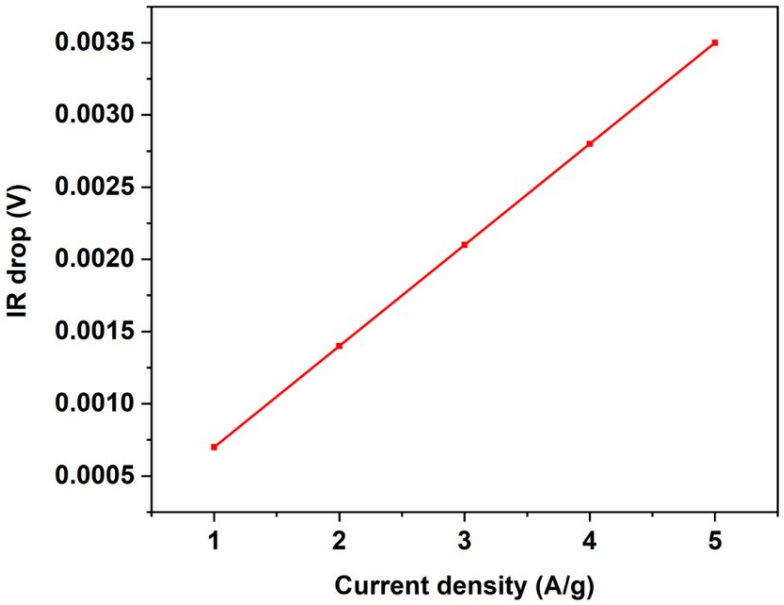

Fig.S5. IR drop for MoO3-S1 at different current density

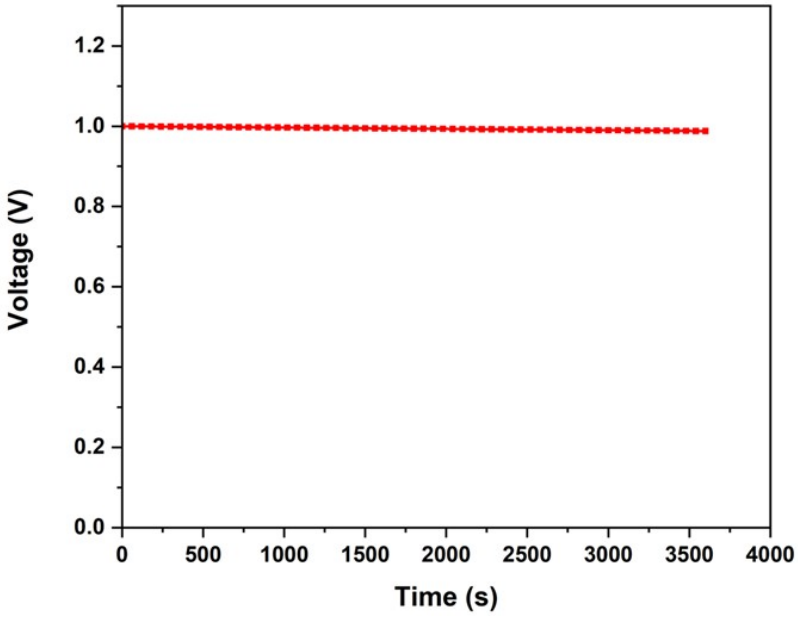

Fig.S6. Self discharging for MoO3-S1 for 1 h.